



# 8A, 600V - 1000V Standard Bridge Rectifier

#### **FEATURES**

- Ideal for printed circuit board
- High case dielectric strength
- High surge current capability
- UL Recognized File # E-326243
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

#### **APPLICATIONS**

- Switching mode power supply
- Adapters
- Lighting application

#### **MECHANICAL DATA**

• Case: D3K

Molding compound meets UL 94V-0 flammability rating

• Terminal: Matte tin plated leads, solderable per J-STD-002

Meet JESD 201 class 1A whisker test

Mounting torque: 0.80 N·m maximum

Polarity: As marked

• Weight: 1.24g (approximately)

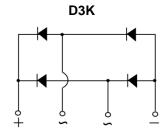
| KEY PARAMETERS   |            |      |  |  |
|------------------|------------|------|--|--|
| PARAMETER        | VALUE      | UNIT |  |  |
| I <sub>F</sub>   | 8          | Α    |  |  |
| $V_{RRM}$        | 600 - 1000 | V    |  |  |
| I <sub>FSM</sub> | 170        | Α    |  |  |
| $T_{JMAX}$       | 150        | °C   |  |  |
| Package          | D3K        |      |  |  |
| Configuration    | Quad       |      |  |  |











| ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)            |                     |              |         |          |                  |
|--|---------------------|--------------|---------|----------|------------------|
| PARAMETER  | SYMBOL              | UR8KB60      | UR8KB80 | UR8KB100 | UNIT             |
| Marking code on the device   |                     | UR8KB60      | UR8KB80 | UR8KB100 |                  |
| Repetitive peak reverse voltage  | $V_{RRM}$           | 600          | 800     | 1000     | V                |
| Reverse voltage, total rms value   | V <sub>R(RMS)</sub> | 420          | 560     | 700      | V                |
| Forward current  | I <sub>F</sub>      | 8            |         |          | Α                |
| Surge peak forward current, 8.3ms single half sine-wave superimposed on rated load | I <sub>FSM</sub>    | 170          |         |          | Α                |
| Rating for fusing (t<8.3ms)  | l <sup>2</sup> t    | 119.9        |         |          | A <sup>2</sup> s |
| Junction temperature   | TJ                  | - 55 to +150 |         | °C       |                  |
| Storage temperature  | T <sub>STG</sub>    | - 55 to +150 |         | °C       |                  |

| THERMAL PERFORMANCE                    |                  |     |      |  |
|--|------------------|-----|------|--|
| PARAMETER                              | SYMBOL           | TYP | UNIT |  |
| Junction-to-lead thermal resistance    | $R_{\Theta JL}$  | 13  | °C/W |  |
| Junction-to-ambient thermal resistance | $R_{\Theta JA}$  | 25  | °C/W |  |
| Junction-to-case thermal resistance    | R <sub>eJC</sub> | 14  | °C/W |  |

Thermal Performance Note: Mounted on heat sink size of 4" x 6" x 0.25" Al-plate

| ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted) |                                |                |      |      |      |
|--|--------------------------------|----------------|------|------|------|
| PARAMETER  | CONDITIONS                     | SYMBOL         | TYP  | MAX  | UNIT |
| Forward voltage per diode <sup>(1)</sup>                                 | $I_F = 4A, T_J = 25^{\circ}C$  | V <sub>F</sub> | 0.93 | 1.10 | V    |
|  | $I_F = 8A, T_J = 25^{\circ}C$  |                | 1.00 | 1.20 | V    |
|  | $I_F = 4A, T_J = 125^{\circ}C$ |                | 0.81 | 1.00 | V    |
|  | $I_F = 8A, T_J = 125^{\circ}C$ |                | 0.90 | 1.10 | V    |
| Reverse current @ rated V <sub>R</sub> per diode <sup>(2)</sup>          | T <sub>J</sub> = 25°C          | I <sub>R</sub> | -    | 10   | μA   |
|  | T <sub>J</sub> = 125°C         |                | 1    | 500  | μA   |
| Junction capacitance per diode   | 1MHz, $V_R = 4.0V$             | CJ             | 63   | -    | pF   |

#### Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

| ORDERING INFORMATION         |         |           |  |  |
|------------------------------|---------|-----------|--|--|
| ORDERING CODE <sup>(1)</sup> | PACKAGE | PACKING   |  |  |
| UR8KBx                       | D3K     | 25 / Tube |  |  |

#### Notes:

1. "x" defines voltage from 600V(UR8KB60) to 1000V(UR8KB100)



#### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

**Fig.1 Forward Current Derating Curve** 

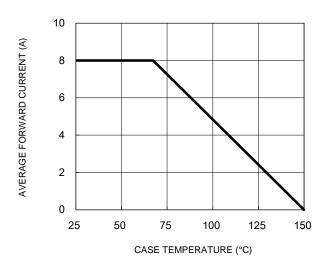
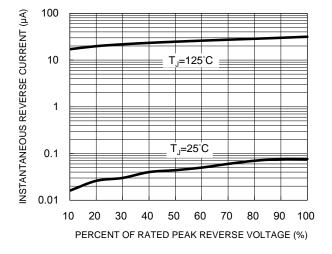


Fig.3 Typical Reverse Characteristics



**Fig.2 Typical Junction Capacitance** 

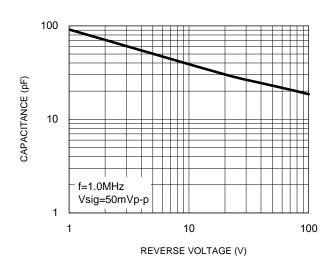
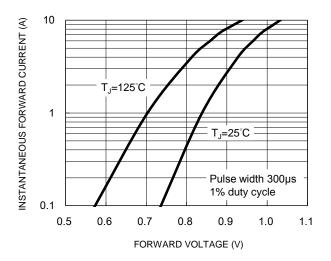


Fig.4 Typical Forward Characteristics

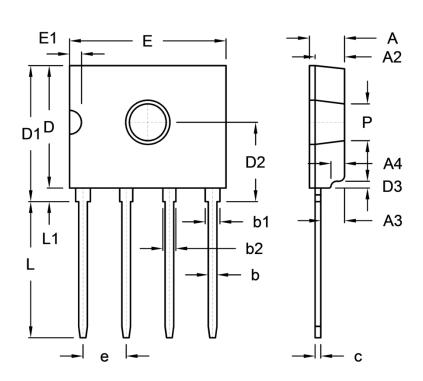




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# **PACKAGE OUTLINE DIMENSIONS**

D3K



| DIM  | DIM. Unit (mm) Min. Max. |       | Unit  | (inch) |  |
|------|--------------------------|-------|-------|--------|--|
| DIM. |                          |       | Min.  | Max.   |  |
| Α    | 2.90                     | 3.30  | 0.114 | 0.130  |  |
| A2   | 2.40                     | 2.80  | 0.094 | 0.110  |  |
| A3   | 1.80                     | 2.40  | 0.071 | 0.094  |  |
| A4   | 1.00                     | 1.40  | 0.039 | 0.055  |  |
| b    | 0.66                     | 0.86  | 0.026 | 0.034  |  |
| b1   | 1.10                     | 1.50  | 0.043 | 0.059  |  |
| b2   | 1.05                     | 1.25  | 0.041 | 0.049  |  |
| С    | 0.40                     | 0.60  | 0.016 | 0.024  |  |
| D    | 10.50                    | 11.10 | 0.413 | 0.437  |  |
| D1   | 11.70                    | 12.30 | 0.461 | 0.484  |  |
| D2   | 6.70                     | 7.30  | 0.264 | 0.287  |  |
| D3   | 0.40                     | 0.80  | 0.016 | 0.031  |  |
| E    | 13.50                    | 14.10 | 0.531 | 0.555  |  |
| E1   | 0.70                     | 1.40  | 0.028 | 0.055  |  |
| е    | 3.51                     | 4.11  | 0.138 | 0.162  |  |
| L    | 11.70                    | 12.30 | 0.461 | 0.484  |  |
| L1   | 1.10                     | 1.40  | 0.043 | 0.055  |  |
| Р    | 3.10                     | 3.40  | 0.122 | 0.134  |  |

### **MARKING DIAGRAM**



P/N = Marking Code

G = Green Compound

YWW = Date Code F = Factory Code



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